

# Exponents of the localization lengths in the bipartite Anderson model with off-diagonal disorder

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## Abstract

We investigate the scaling properties of the two-dimensional (2D) Anderson model of localization with purely off-diagonal disorder (random hopping). In particular, we show that for small energies the infinite-size localization lengths as computed from transfer-matrix methods together with finite-size scaling diverge with a power-law behavior. The corresponding exponents seem to depend on the strength and the type of disorder chosen.

*Key words:* Localization, off-diagonal disorder, critical exponents, bipartiteness

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## 1. Introduction

Of paramount importance for the theory of disordered systems and the concept of Anderson localization [1–5] is the scaling theory of localization as proposed in 1979 [6]. Especially in 2D, this theory predicts the absence of a disorder-driven MIT for generic situations such that all states remain localized and the system is an insulator [7–9]. However, already early [10,11] it was suggested that an Anderson model of localization with purely off-diagonal disorder might violate this general statement since non-localized states were found at the band center [12–14]. Further numerical investiga-

tions in recent years [15–19] have uncovered additional evidence that the localization properties at  $E = 0$  are special. In particular, it was found that the divergence in the density of states DOS is accompanied by a divergence of the localization lengths  $\lambda$  [15,16]. This divergence does not violate the scaling arguments [20], since it can be shown that its scaling properties are compatible with critical states only [16], i.e., there are no truly extended states at  $E = 0$ . Of importance for the model is a very special symmetry around  $E = 0$  which holds in the bipartite case of an even number of sites [20,21]. Then the spectrum is symmetric such that for every eigenenergy  $E_i < 0$  there is also a state with energy  $E_i > 0$ . This situation is connected with a so-called chiral universality class. Furthermore, the model is closely connected to the random flux model studied in the quantum-Hall situation

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where the off-diagonal disorder is due to a random magnetic flux through the 2D plaquettes.

Thus although we do not have a true MIT, we nevertheless have a transition from localized via delocalized to localized behavior as we sweep the energy through  $E = 0$ . We consider a single electron on the 2D lattice with  $N$  sites described by the Anderson Hamiltonian

$$H = \sum_{i \neq j}^N t_{ij} |i\rangle \langle j| + \sum_i^N \epsilon_i |i\rangle \langle i| \quad (1)$$

where  $|i\rangle$  denotes the electron at site  $i$ . The onsite energies  $\epsilon_i$  are set to 0 and the off-diagonal disorder is introduced by choosing random hopping elements  $t_{ij}$  between nearest neighbor sites.

We test three different distributions of  $t_{ij}$ : (i) a rectangular distribution  $t_{ij} \in [c - w/2, c + w/2]$  [15], (ii) a Gaussian distribution  $P(t_{ij}) = \exp[-(t_{ij} - c)^2/2\sigma^2]/\sqrt{2\pi\sigma^2}$ , and (iii) a rectangular distribution of the logarithm of  $t_{ij}$  where  $P(\ln t_{ij}/t_0) = 1/w$  if  $|\ln t_{ij}/t_0| \leq w/2$  or  $P(\ln t_{ij}/t_0) = 0$  otherwise [14]. The logarithmic distribution appears more suited to model actual physical systems [14]. We also note that the logarithmic distribution avoids problems with zero  $t$  elements and thus there is no need to introduce an artificial lower cutoff as for the box and Gaussian distributions [15]. Furthermore, the box and Gaussian distributions will usually have negative  $t$  values which correspond to a rather artificial phase shift.

In the case of rectangular and normal distributions we set the width  $w$  and the standard deviation  $\sigma$  to 1 and change the center  $c$  of the distribution. In the case of the logarithmic  $t$  distribution  $t_0 = 1$  sets the energy scale and we change the disorder width  $w$ . Values of the parameters were  $c = 0, 0.25, 0.5$ , and  $1.0$  for the rectangular distribution;  $c = 0$  and  $c = 0.25$  for the Gaussian distribution and  $w = 2, 6$ , and  $10$  for the logarithmic  $t$  distribution.

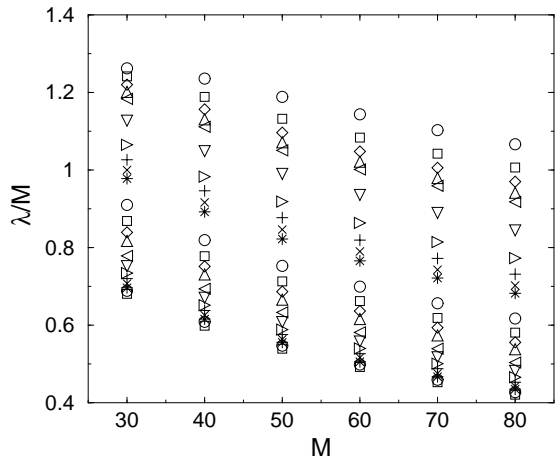


Fig. 1. Reduced localization length  $\lambda/M$  for various system sizes  $M$  of a box  $t$  distribution with  $c = 0$ . Symbols indicate different energies ranging from  $0.025$  ( $\circ$ ),  $0.0225$  ( $\square$ ) to  $2 \times 10^{-5}$  ( $\square$ ).

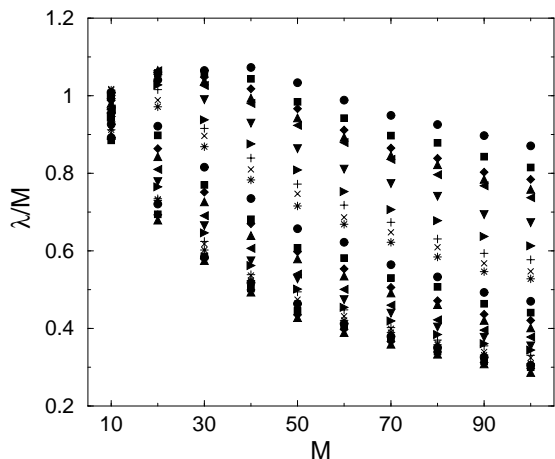


Fig. 2. Reduced localization length  $\lambda/M$  for various system sizes  $M$  of a Gaussian  $t$  distribution with  $c = 0.25$ . Symbols indicate different energies ranging from  $0.03$  ( $\bullet$ ),  $0.0275$  ( $\blacksquare$ ) to  $2 \times 10^{-5}$  ( $\blacktriangle$ ).

## 2. Computation of the localization lengths at $E \neq 0$

The transfer-matrix method [22,23] was used to compute the localization lengths for strips of various widths  $M$  up to  $M = 100$  in the energy interval  $2 \times 10^{-5} \leq E \leq 0.2048$ . In Figs. 1, 2, and 3 we

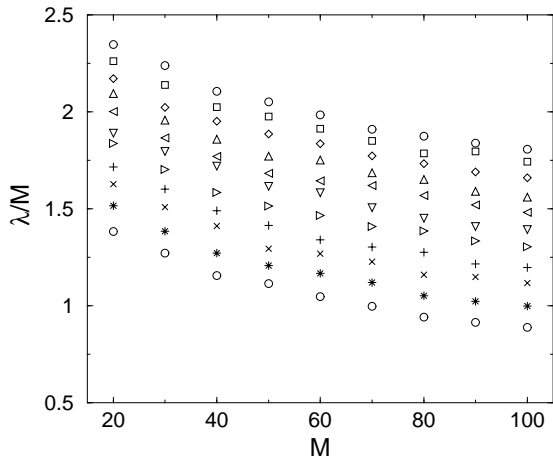


Fig. 3. Reduced localization length  $\lambda/M$  for various system sizes  $M$  of a logarithmic  $t$  distribution with  $w = 2$ . Symbols indicate different energies ranging from 0.2048 ( $\circ$ ), 0.1024 ( $\square$ ) to  $2 \times 10^{-4}$  ( $\square$ ).

show the system size dependence for, e.g., special values of  $c$  and  $w$  and all three disorder distributions. The accuracy of our results was 0.1–0.3% or 1% depending on the disorder distribution and the values of parameters, see Table 1 for actual parameter values. Next, the finite-size-scaling analysis of Ref. [23] was applied to the data. The calculated localization lengths usually increase as the energy approaches 0. Only, for small even width values (10, 20) it decreases significantly close to  $E = 0$  [19] which makes finite-size scaling impossible. Therefore the smallest system sizes were dropped during the finite-size scaling procedure. Results for the finite-size scaling curves are shown in Fig. 4 for the three different distributions.

### 3. Critical exponents

One expects that the scaling parameters  $\xi$  obtained from finite-size scaling diverge close to  $E = 0$  [24]. However, the precise functional form of this divergence is not yet known. In Ref. [24] it has been suggested that for energies  $E > E^*$  the divergence can be described by a power law as

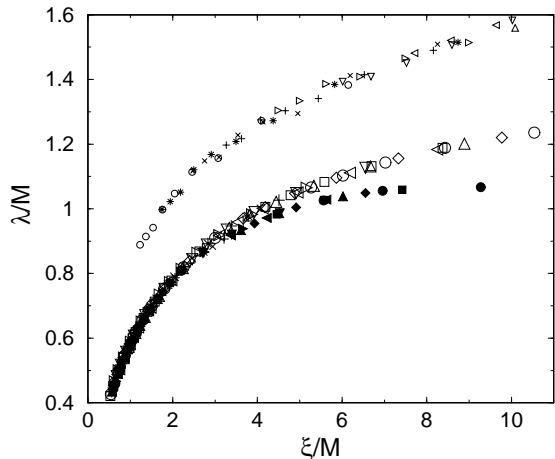


Fig. 4. Finite-size-scaling plots for box ( $c = 0$ ,  $M \in [50, 80]$ , large open symbols), Gaussian ( $c = 0$ ,  $M \in [20, 60]$ , filled symbols), and logarithmic ( $w = 2$ ,  $M \in [30, 100]$ , small open symbols)  $t$  distributions.

$$\xi(E) \propto \left| \frac{E_0}{E} \right|^\nu \quad (2)$$

with the critical exponent  $\nu$ . For even smaller  $|E| \ll E^*$ , this behavior should then change to

$$\xi(E) \propto \exp \sqrt{\frac{\ln E_0/E}{A}} \quad (3)$$

with constants  $E_0$  and  $A$  given by the renormalization group flow [24]. Double-logarithmic plots of  $\xi$  vs.  $E$  in Figs. 5, 6 and 7 confirm the power-law behavior with reasonable accuracy down to  $E \approx 10^{-4}$ . For smaller values it has been shown already in Ref. [19] that a new behavior is to be expected.

Table 1 collects the values of the critical exponent obtained for different disorders. In the case of the logarithmic  $t$  distribution and  $w = 10$  the power-law divergence fails, therefore the exponent was not calculated. From Table 1, it can be easily seen that all calculated values are in the range  $0.2 \leq \nu \leq 0.5$ . The exponent is apparently not universal but seems to depend on the kind of disorder and the actual value of parameters; for stronger disorders  $\nu$  becomes smaller (for the logarithmic  $t$  distribution the disorder strength increases with  $w$  [14], for the rectangular distribution the strongest disorder appears at  $c = 0.25$

Table 1

Estimated values of the exponents of the localization lengths for various disorder strengths and distributions. The error bars represent the standard deviations from the power-law fit and should be increased by at least one order of magnitude for a reliable representation of the actual errors.

disorder distribution	parameters	accuracy in %	sizes used in finite-size scaling	estimated exponent
box	$c = 0$	0.1-0.2	30-80	$0.326 \pm 0.002$
box	$c = 0$	0.1-0.2	25-65	$0.325 \pm 0.002$
box	$c = 0.25$	0.1-0.2	30-70	$0.319 \pm 0.001$
box	$c = 0.5$	0.1-0.2	30-70	$0.361 \pm 0.001$
box	$c = 1.0$	0.1-0.3	30-70	$0.444 \pm 0.002$
Gaussian	$c = 0$	0.1-0.2	30-60	$0.314 \pm 0.001$
Gaussian	$c = 0.25$	1	30-100	$0.310 \pm 0.001$
Gaussian	$c = 0.25$	1	35-95	$0.308 \pm 0.001$
logarithmic	$w = 2$	1	20-100	$0.412 \pm 0.007$
logarithmic	$w = 6$	1	20-100	$0.251 \pm 0.004$
logarithmic	$w = 10$	1	20-100	—

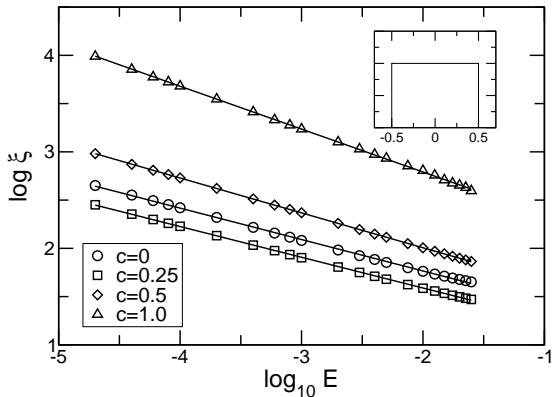


Fig. 5. Variation of the infinite-size localization length  $\xi$  with  $E$  for box distributions. The inset shows the  $t$  distribution for  $c = 0$ .

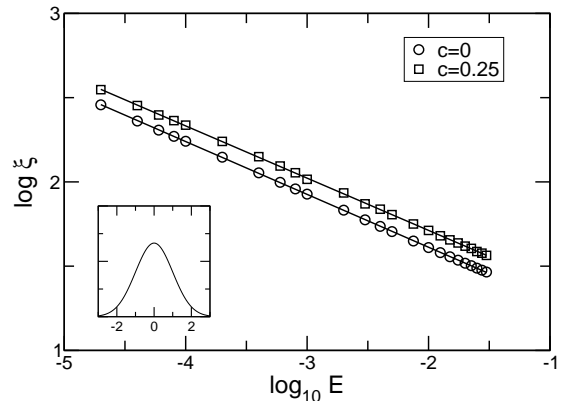


Fig. 6. Variation of the infinite-size localization length  $\xi$  with  $E$  for Gaussian distributions. The inset shows the  $t$  distribution for  $c = 0$ .

[15]). This non-universality is in agreement with the results of Ref. [24].

As the localization lengths calculated for odd and even strip widths may exhibit different behavior [14,19] we repeated the procedure also for some odd-width systems for rectangular and Gaussian distributions. The difference is within error bars, thus for these disorder strengths the effect is negligible.

#### 4. Conclusions

Our results suggest that the localization-delocalization-localization present in the off-diagonal Anderson model of localization in 2D can be described by a set of exponents that model the divergence of the localization lengths  $\xi$  at  $E = 0$ . Note that these exponents are in reasonable agreement with the exponent 0.5 first estimated for the scaling of the participation numbers in Ref. [15]. Down to  $E \approx 10^{-4}$  the power-law behavior can model the data reasonably well. Thus we ex-

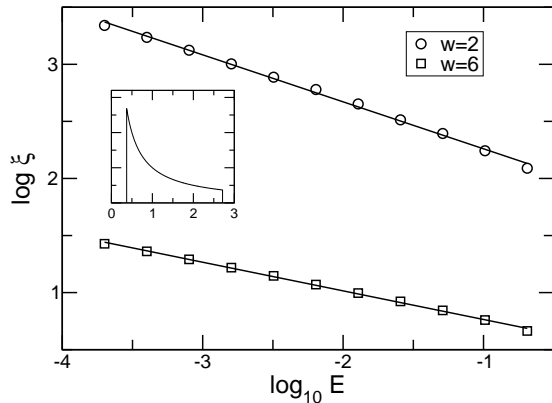


Fig. 7. Variation of the infinite-size localization length  $\xi$  with  $E$  for logarithmic distributions. The inset shows the  $t$  distribution for  $w = 2$ .

pect the crossover predicted in Ref. [24] to appear at smaller energies. We find that the exponents depend on the strength and distribution of the off-diagonal disorder also in agreement with Ref. [24]. Currently, we are extending these calculations to smaller energies.

We note that it might be interesting to also investigate the situation in honeycomb lattices [25], where the van Hove singularity of the square lattice at  $E = 0$  does not interfere with the divergence due to the bipartiteness which is of interest here.

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